Anomalous Geometry in u-Oxo and u-Nitrido Com**pounds of Silicon, Phosphorus, Sulphur, and their Heavier Congeners: Stereochemical Inactivity of Lone Pairs in the Presence of Ligands of Low Electronegativity**

C. GLIDEWELL

Chemistry Department, University of St. Andrews, St. Andrews, Fife K YI 6 9ST, Scotland, U.K. Received June 5. 1978

In μ -oxo and μ -nitrido compounds of silicon, phosphorus, sulphur, and their heavier congeners of types $O(MR_n)_2$ and $N(MR_n)_3$, the inter-bond angles at oxygen and nitrogen are generally much larger than those predicted by the VSEPR model. The lower limiting values of the angles $\triangle MOM$ and $\triangle MNM$ can usually be predicted by a hard-atom model [l] but this model cannot account for the linearity at oxygen observed in, for example, certain disilicates [2], $O(SiPh_3)_2$ [3], $K_2Pb_2Ge_2O_7$ [4], and the β -phases of a number of diphosphates [5] ; and the question naturally arises why these species should contain linear MOM fragments.

This question is most readily answered by reversing it and enquiring in turn why most oxo compounds $O(MR_n)_2$ (in which M is p-block element and n ranges from O-3) are in fact non-linear at oxygen. Pearson has shown $[6, 7]$ that the theoretical justification of the VSEPR model can be derived by the use of the second-order Jahn-Teller (SOJT) effect. In terms of the SOJT effect, any linear AX_2 species containing one or two (but not three) pairs of non bonding electrons localised in A will normally be unstable to bending; while an AX_3 species containing a single non-bonding pair localised on A will normally be unstable with respect to distortion along the out of plane bend (the umbrella vibration), giving a pyramidal skeleton.

It must be emphasised that these conclusions are valid only when the valence shell orbitals of the ligand atom X are bound at least as tightly as those of the central atom A. When the ligand atom orbitals are less tightly bound *(i.e.* are less electronegative) than those of A, no distortion from linearity of AX_2 or from planarity of AX_3 is expected; and consequently the lone pair or pairs on A are stereochemically inactive.

Suppose for simplicity that in $A(MR_n)_2$, the central atom A contributes ns and np valence-shell orbitals, while the ligands MR_n each contribute a single σ type orbital. Then for linear $A(MR_n)_2$ in which A bears two lone pairs, the electronic configuration is

 $(1\sigma_{\sigma}^{+})^{2}(1\sigma_{\sigma}^{+})^{2}(1\pi_{\nu})^{4}(2\sigma_{\sigma}^{+})^{0}(2\sigma_{\nu}^{+})^{0}$

The principal factor which determines whether the linear configuration is stable with respect to bending is the energy gap $I(1\pi_u) \leftrightarrow I(2\sigma_g)$: if this is large [6, 71, the system remains linear, but if it is small, distortion will occur along a vibration of symmetry $\Pi_{\mathbf{u}} \times \Sigma_{\mathbf{g}}^* = \Pi_{\mathbf{u}}$; that is, along the skeletal bending vibration. Since $1\pi_{\text{u}}$ is localised exclusively on the central atom, then the less tightly bound are the ligand orbitals relative to those of the central atom, the bigger will be the crucial gap between $1\pi_u$ and $2\sigma_g^*$, and the smaller the tendency of the skeleton to bend. Conversely, when the ligand σ orbitals are bound tighter than those of the central atom, the $(1\pi_{\mathbf{u}})$ $2(\sigma_{\mathbf{z}}^{\dagger})$ gap is small, so that the system bends along the $\Pi_{\mathbf{u}}$ vibration.

Similarly in $A(MR_n)_3$, using the same orbitals, the electronic configuration for a planar $AM₃$ skeleton bearing a lone pair on A is

$$
(1a'_1)^2(1e')^4(1a''_2)^2(2a'_1)^0(2e')^0
$$

Here the important energy gap is between $1a''_2$ and $2a'_1$: if this is small, as occurs when the ligand orbitals are the tighter bound, the system distorts along a vibration of symmetry $A_2^{\prime\prime} \times A_1^{\prime} = A_2^{\prime\prime}$; that is along the out of plane bend. However when the ligand orbitals are the less tightly bound, the $(la_2''-(2a_1'))$ gap is large, and no distortion from planarity occurs. Hence the linearity of $O(MR_n)_2$ and the planarity of $N(MR_n)_3$ may be understood in solely electronic terms, provided only that MR_n is of low electronegativity.

It has previously been deduced [8] from the ionisation energies of compounds AH_n and $A(MH_3)_n$ $(M = C, Si, Ge: A = Cl, Br, I; n = 1; A = O, S, Se; n =$ 2; A = N, P, As; n = 3: A = NCO, NCS, N₃; n = 1) that $SiH₃$ and $GeH₃$ are electron donors, rather than electron acceptors as has been generally supposed [9]. Similarly, it is scarcely conceivable that SiO_3^{-2} and $GeO₃⁻²$ are electron acceptors: in support of the view that they are electron donors, it may be noted that in species $O(MO_3)_2^{-2n}$ when M runs from Si (n = 3) through P and S to Cl (n = 0), as the electroneg tivity of $MO_3^{-(n-1)}$ increases and the $(1\pi_u)-(2\sigma_g)$ gap in the linear $O(MO_3)z^{2n}$ decreases, so also the interbond angle at oxygen steadily decreases, in each case limited by the $M \cdots M$ distance.

We wish to suggest that the anomalous geometries observed in μ -oxo and μ -nitrido compounds of silicon, phosphorus, and sulphur, and their heavier congeners are a consequence not of the electron acceptor properties of the MR_n groups *via* π donation from p orbitals of oxygen or nitrogen to d orbitals of M [9, IO], but rather of the electron donor properties of MR_n which substantially weaken the tendency of the linear $O(MR_n)_2$ and the planar $N(MR_n)_3$ to distort by means of the SOJT effect. The hard-atom contact distances $M \cdots M$ [1] are thus to be regarded not as subtending an angle at oxygen or nitrogen which is expanded from its approximately tetrahedral VSEPR value, but as limiting the extent to which a weak bending force distorts a linear or planar molecule.

References

- 1 C. Glidewell, Inorg *Chim. Acta, 12, 219 (1975);20, 113 (1976).*
- *2* D. W. J. Cruickshank, H. Lynton and G. A. Barclay, *Acta @wt., 15, 491 (1962); Yu. I.* Smolin and Yu. F. Shepelev, *Acta Ctyst., 826, 454 (1970); Yu. I.* Smolin, Yu. F. Shepelev and A. P. Titov, *Kristallografiya, 17,851(1972);* G. B. Ansell and B. Wanklyn, Chem. Comm., 794 (1975).
- 3 C. Glidewell and D. C. Liles, *Acta Cryst., B34, 124 (1978).*
- *4 G.* Bassi and J. Lajzerowicz, *Bull. Sot. Fr. Mineral Czist., 88, 342 (1965).*
- *5 C.* Calvo, *Cznad. J. Chem.,* 43, 1139 (1965); 43, 1147 (1965); B. E. Robertson and C. Calvo, *Canad. J. Chem.,* ¹6, 605 (1968); G. R. Levi and G. Peyronel, Z. *Krist.*, 92; 190 (i935):'
- 6 R. G. Pearson, *J. Am. Chem. Sot., 91, 4947 (1969).*
- *7* R. G. Pearson, "Symmetry Rules for Chemical Reactions", Wiley-Interscience, New York (1976).
- 8 C. Glidewell, *Inorg. Chim. Acta, 13,* Lll (1975).
- 9 E. A. V. Ebsworth in "Organometallic Compounds of the Group IV Elements", A. G. MacDonald (ed.), Dekker, New York, *1,* 1 (1968).
- 10 D. W. J. Cruickshank, J. Chem. Soc., 5486 (1961).